TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7PG34AFE

Dual NON-Inverter

Features

• High-level output current: $I_{OH}/I_{OL} = \pm 8 \text{ mA (min)}$

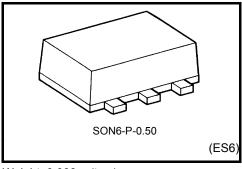
at $V_{CC} = 3 V$

• High-speed operation: t_{pd} = 2.8 ns (typ.)

at $V_{CC} = 3.3 \text{ V}, 15 \text{pF}$

• Operating voltage range: V_{CC} = 0.9~3.6 V

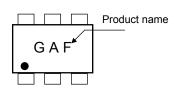
• 5.5-V tolerant inputs

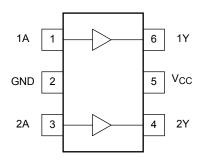


Weight: 0.003 g (typ.)

Marking

Pin Assignment (top view)





Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Value	Unit
Power supply voltage	V _{CC}	-0.5~4.6	V
DC input voltage	V _{IN}	-0.5~7.0	V
DC output voltage	V _{OUT}	-0.5~V _{CC} + 0.5	V
Input diode current	lıK	-20	mA
Output diode current	lok	±20 (Note 1)	mA
DC output current	lout	±25	mA
DC V _{CC} /GND current	Icc	±100	mA
Power dissipation	PD	150	mW
Storage temperature	T _{stg}	-65~150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: V_{OUT} < GND, V_{OUT} > V_{CC}

IEC Logic Symbol



Truth Table

Α	Y
L	L
Н	Н

Operating Range

Characteristics	Symbol	Value	Unit
Power supply voltage	V _{CC}	0.9~3.6	V
Input voltage	V _{IN}	0~5.5	V
Output voltage	V _{OUT}	0~V _{CC}	V
Output Current	I _{OH} /I _{OL}	±8.0 (Note 2)	
		±4.0 (Note 3)	
		±3.0 (Note 4)	mΛ
		±1.7 (Note 5)	mA
		±0.3 (Note 6)	
		±0.02 (Note 7)	
Operating temperature	T _{opr}	-40~85	°C
Input rise and fall time	dt/dV	0~10 (Note 8)	ns/V

Note 2: V_{CC} = 3.0~3.6 V

Note 3: $V_{CC} = 2.3 \sim 2.7 \text{ V}$

Note 4: $V_{CC} = 1.65 \sim 1.95 \text{ V}$

Note 5: V_{CC} = 1.4~1.6 V

Note 6: V_{CC} = 1.1~1.3 V

Note 7: $V_{CC} = 0.9 V$

Note 8: $V_{IN} = 0.8 \sim 2.0 \text{ V}, V_{CC} = 3.0 \text{ V}$

Electrical Characteristics

DC Electrical Characteristics

Characteristics Symbol Test Condition				Ta = 25°C			Ta = -40~85°C		11114	
Characteristics Symbol		rest	Test Condition V _{CC} (V)		Min	Тур.	Max	Min	Max	Unit
High-level VIH input voltage			0.9	V _{CC}	_	_	V _C C	_		
				V _{CC} × 0.7	_	_	V _{CC} × 0.7		V	
	_		1.4~1.6	V _{CC} × 0.65	_	_	V _{CC} × 0.65			
				V _{CC} × 0.65		_	V _{CC} × 0.65			
			2.3~2.7	1.7	_	_	1.7	_		
				2.0	_	_	2.0	_		
					_	_	GND	—	GND	
Low-level V _{IL}			1.1~1.3	_	_	V _{CC} × 0.3	_	V _{CC} × 0.3	V	
		_	1.4~1.6			V _{CC} × 0.35	_	V _{CC} × 0.35		
input voltage				1.65~1.95			V _{CC} × 0.35	_	V _{CC} × 0.35	
			2.3~2.7	_	_	0.7		0.7		
			3.0~3.6	_	_	0.8		0.8		
			I _{OH} =-0.02 mA	0.9	0.75	_	_	0.75		
High-level Voh Vin		$I_{OH} = -0.3 \text{ mA}$	1.1~1.3	V _{CC} × 0.75	1	_	V _{CC} × 0.75	l	V	
	V _{IN} = V _{IH}	$I_{OH} = -1.7 \text{ mA}$	1.4~1.6	V _{CC} × 0.75		_	V _{CC} × 0.75			
output voltage			I _{OH} = -3.0 mA	1.65~ 1.95	V _{CC} -0.45	_	_	V _{CC} -0.45	_	
		$I_{OH} = -4.0 \text{ mA}$		2.3~2.7	2.0	_	_	2.0	_	
			I _{OH} = -8.0 mA	3.0~3.6	2.48	_	_	2.48	_	
			$I_{OL} = 0.02 \text{ mA}$	0.9	_	_	0.1	_	0.1	
Low-level $V_{OL} \qquad V_{IN} = V$ output voltage		I _{OL} = 0.3 mA	1.1~1.3			V _{CC} × 0.25	_	V _{CC} × 0.25	5	
	$V_{IN} = V_{IL}$	I _{OL} = 1.7 mA	1.4~1.6		_	V _{CC} × 0.25	_	V _{CC} × 0.25	V	
		I _{OL} = 3.0 mA	1.65~ 1.95		_	0.45	_	0.45		
	$I_{OL} = 4.0 \text{ mA}$ $I_{OL} = 8.0 \text{ mA}$	2.3~2.7	_	_	0.4	_	0.4			
		I _{OL} = 8.0 mA	3.0~3.6	_	_	0.4	_	0.4		
Input leakage current	I _{IN}	V _{IN} = 0~5.5V		0~3.6	_	_	±0.1	_	±1.0	μΑ
Quiescent supply current	Icc	V _{IN} = V _{CC}	or GND	3.6	_	_	1.0	_	10.0	μΑ

AC Electrical Characteristics (input $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition		Т		Га = 25°C		Ta = -40~85°C	
			V _{CC} (V)	Min	Тур.	Max	Min	Max	Unit
		C _L = 10 pF,	0.9	_	27.2	_	_	_	-
			1.1~1.3	_	12.2	23.2	1.0	42.6	
			1.4~1.6		6.5	10.2	1.0	12.0	
		$R_L = 1 M\Omega$	1.65~ 1.95		4.7	7.0	1.0	7.6	
			2.3~2.7		3.1	4.4	1.0	4.9	
	^t pLH ^t pHL		3.0~3.6		2.4	3.5	1.0	4.1	
		C_L = 15 pF, R_L = 1 M Ω	0.9		29.8		_	_	ns
			1.1~1.3	_	13.5	26.0	1.0	44.5	
Propagation delay time			1.4~1.6	_	7.2	11.4	1.0	13.6	
Tropagation delay time			1.65~ 1.95		5.2	7.5	1.0	7.7	
			2.3~2.7	_	3.4	4.8	1.0	5.5	
			3.0~3.6		2.8	3.8	1.0	4.4	
		$C_L = 30 \text{ pF},$ $R_L = 1 \text{ M}\Omega$	0.9		40.7		_	_	
			1.1~1.3		17.8	33.9	1.0	64.1	
			1.4~1.6		9.1	14.3	1.0	17.4	
			1.65~ 1.95		6.6	9.8	1.0	10.2	
			2.3~2.7		4.1	6.2	1.0	6.6	
			3.0~3.6		3.3	4.8	1.0	5.2	
Input capacitance	C _{IN}		3.6		3	_	_	_	pF
Power dissipation capacitance	C_{PD}	(Note 9)	0.9 ~ 3.6	_	6	_	_	_	pF

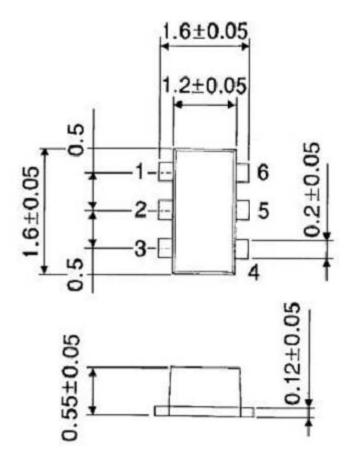
Note 9: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC \text{ (opr.)}} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/2$

Package Dimensions

SON6-P-0.50 Unit: mm



Weight: 0.003 g (typ.)

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20070701-EN GENERAL

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